

Serial EEPROM Series Automotive EEPROM

125°C Operation Microwire BUS EEPROM (3-wire)

BR93H66-2C

General Description

BR93H66-2C is a serial EEPROM of serial 3-line interface method.

Features

- Conforming to Microwire BUS
- Withstands Electrostatic Voltage up to 6kV (HBM method typ)
- Wide Temperature Range -40°C to +125°C
- Same package line-up and same pin configuration
- 2.5V to 5.5V Single Supply Voltage Operation
- Address Auto Increment Function at READ Operation
- Prevention of write mistake
 - > Write prohibition at power on
 - > Write prohibition by command code
 - > Write mistake prevention circuit at low voltage
- Self-timed programming cycle
- Program Condition Display by READY / BUSY
- Low Supply Current
 - Write Operation (5V): 0.8mA (Typ)
 - Read Operation (5V): 0.5mA (Typ)
 - > Standby Operation (5V): 0.1µA (Typ)
- Compact package MSOP8 / TSSOP-B8 / SOP8 / SOP-J8
- High-Reliability using ROHM Original Double-Cell Structure
- More than 50 years data retention (Ta≦125°C)
- More than 300,000 write cycles (Ta≦125°C)
- Data set to FFFFh on all addresses at shipment
- AEC-Q100 Qualified

Packages MSOP8 TSSOP-B8 SOP8 SOP-J8

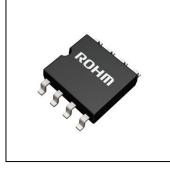
(Max) (Typ) 2.90mm x 4.00mm x 0.90mm 3.00mm x 6.40mm x 1.20mm 5.00mm x 6.20mm x 1.71mm 4.90mm x 6.00mm x 1.65mm

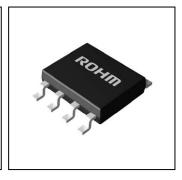




MSOP8

TSSOP-B8





SOP8

SOP-J8

BR93H66-2C

•	711301100 20	<u> </u>						
		Pa	MSOP8	TSSOP-B8	SOP8	SOP-J8		
	Capacity	Bit Format	Product Name	Supply Voltage	RFVM	RFVT	RF	RFJ
	4Kbit	256 × 16	BR93H66-2C	2.5V to 5.5V	•	•	•	•

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply Voltage	Vcc	-0.3 to +6.5	V
		380 (MSOP8) ⁽¹⁾	
Demaissible Dissipation	D4	410 (TSSOP-B8) (2)	\/
Permissible Dissipation	Pd	560 (SOP8) (3)	mW
		560 (SOP-J8) (4)	
Storage Temperature Range	T _{stg}	-65 to +150 °C	
Operating Temperature Range	T _{opr}	-40 to +125	°C
Input Voltage/Output Voltage	-	-0.3 to VCC+0.3	V

⁽¹⁾When using at Ta=25°C or higher, 3.1mW(*1), 3.3mW(2), 4.5mW(3,4),to be reduced per 1°C.

Memory Cell Characteristics (V_{CC}=2.5V to 5.5V)

Darameter		Limits	Unit	Conditions	
Parameter	Min	Тур	Max	Unit	
	1,000,000	-	-	Cycles	Ta≦85°C
Write Cycles (5)	500,000	-	-	Cycles	Ta≦105°C
	300,000	-	-	Cycles	Ta≦125°C
	100	-	-	Years	Ta≦25°C
Data Retention (5)	60	-	-	Years	Ta≦105°C
	50	-	-	Years	Ta≦125°C

⁽⁵⁾ Not 100% TESTED

Recommended Action Conditions

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Parameter	Symbol	Limits	Unit			
Supply Voltage	V _{CC}	2.5 to 5.5	V			
Input Voltage	VIN	0 to Vcc	V			

DC Characteristics (Unless otherwise specified, Ta=-40°C to +125°C, Vcc=2.5V to 5.5V)

		Limits		120 0, 100		Conditions
Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Input Low Voltage	VIL	-0.3	-	0.3xVcc	V	
Input High Voltage	V _{IH}	0.7xVcc	-	Vcc+0.3	V	
Output Low Voltage 1	V _{OL1}	0	-	0.4	V	I _{OL} =2.1mA, 4.0V≦V _{CC} ≦5.5V
Output Low Voltage 2	V _{OL2}	0	-	0.2	V	Ι _{ΟL} =100μΑ
Output High Voltage 1	V _{OH1}	2.4	-	Vcc	V	I _{OH} =-0.4mA, 4.0V≦V _{CC} ≦5.5V
Output High Voltage 2	V _{OH2}	V _{CC} -0.2	-	Vcc	V	I _{OH} =-100μA
Input Leak Current	ILI	-10	-	10	μA	V _{IN} =0V to V _{CC}
Output Leak Current	ILO	-10	-	10	μA	V _{OUT} =0V to V _{CC} , CS=0V
	I _{CC1}	-	-	3.0	mA	f _{SK} =2MHz, tE/w=4ms (WRITE)
Supply Current	Icc2	-	-	1.5	mA	f _{SK} =2MHz (READ)
	Іссз	-	-	3.0	mA	f _{SK} =2MHz, t _{EW} =4ms (WRAL)
Standby Current	I _{SB}	-	-	10	μA	CS=0V, DO=OPEN

AC Characteristics (Unless otherwise specified, Ta=-40°C to +125°C, Vcc=2.5V to 5.5V)

Parameter	Symbol	Min.	Тур.	Max.	Unit
SK Frequency	fsk	-	-	2	MHz
SK "H" Time	tsкн	200	-	-	ns
SK "L" Time	tskL	200	-	-	ns
CS "L" Time	tcs	200	-	-	ns
CS Setup Time	tcss	50	-	-	ns
DI Setup Time	t _{DIS}	50	-	-	ns
CS Hold Time	tсsн	0	-	-	ns
DI Hold Time	tын	50	-	-	ns
Data "1" Output Delay Time	t _{PD1}	-	-	200	ns
Data "0" Output Delay Time	t _{PD0}	-	-	200	ns
Time from CS to Output establishment	t _{SV}	-	-	150	ns
Time from CS to High-Z	tof	-	-	150	ns
Write Cycle Time	tew	-	-	4	ms

Serial Input / Output Timing

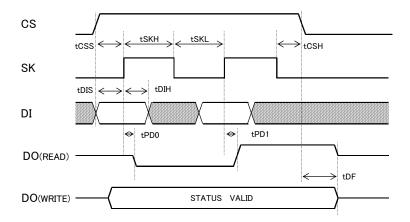


Figure 1. Serial Input / Output Timing Diagram

- 1. Data is taken from DI, in sync with the rise of SK.
- 2. At READ command, data is outputted from DO in sync with the rise of SK.
- 3. After WRITE command input, the status signal of WRITE (READY / BUSY) can be monitored from DO by setting CS to "H" after tCS, from the fall of CS, and will display a valid status until the next command start bit is inputted. But, if CS is set to "L", DO sets to High-Z state.
- 4. To execute a series of commands, CS is set to "L" once after completion of each command for internal circuit reset.

Block Diagram

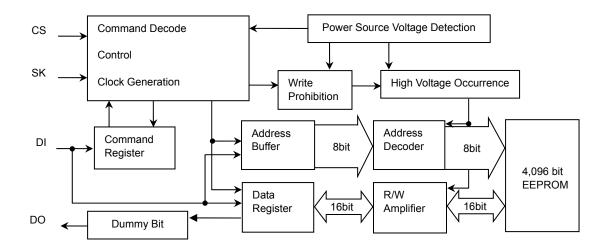


Figure 2. Block Diagram

Pin Configuration

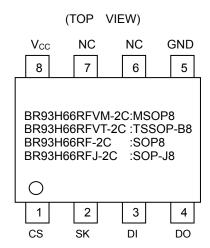


Figure 3. Pin Configuration

Pin Descriptions

Pin Number	Pin Name	1/0	Function	
1	CS	Input	Chip select input	
2	SK	Input	Serial clock input	
3	DI	Input	Start bit, ope code, address, and serial data input	
4	DO	Output	Serial data output, READY / BUSY status output	
5	GND	-	Ground, 0V	
6,7	NC	-	Non connected terminal, Vcc, GND or OPEN	
8	VCC	-	Power supply, 2.5V to 5.5V	

Typical Performance Curves

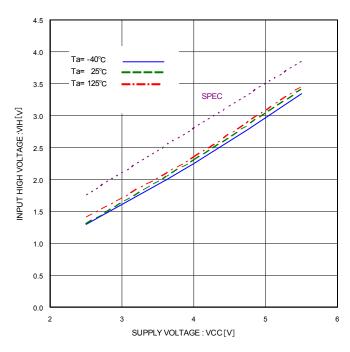


Figure 4. Input High Voltage (CS,SK,DI) vs. Supply Voltage

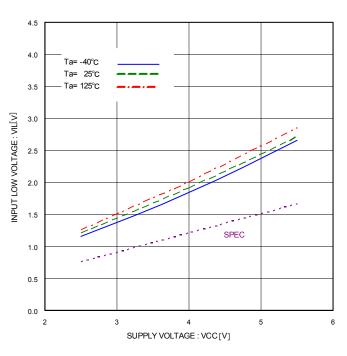


Figure 5. Input Low Voltage (CS,SK,DI) vs. Supply Voltage

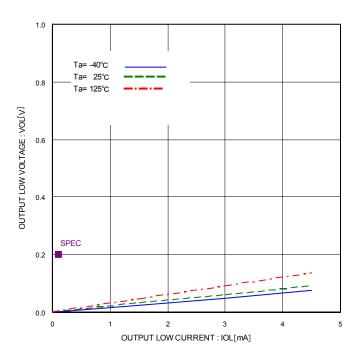


Figure 6. Output Low Voltage vs. Output Low Current $(V_{CC}=2.5V)$

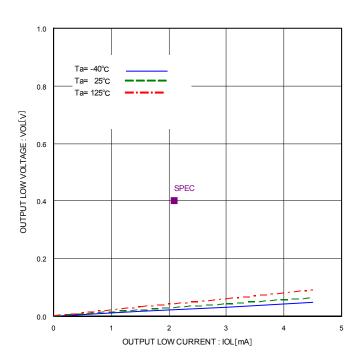
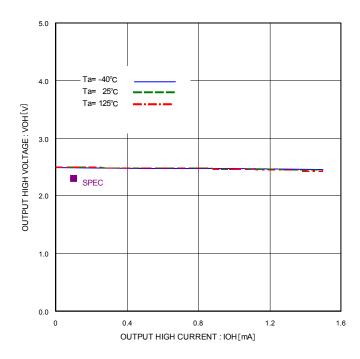


Figure 7. Output Low Voltage vs. Output Low Current (Vcc=4.0V)



5.0

4.0

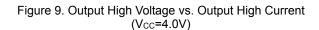
4.0

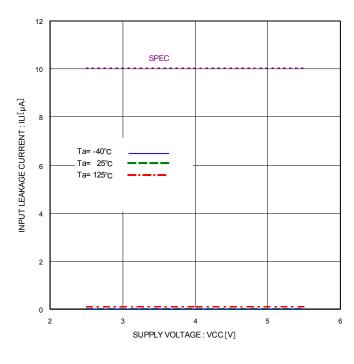
Ta=-40°C

Ta= 25°C

Ta= 125°C

Figure 8. Output High Voltage vs. Output High Current (Vcc=2.5V)





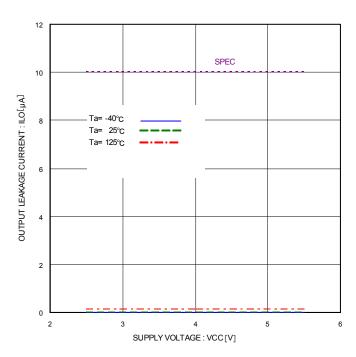


Figure 10. Input Leak Current (CS,SK,DI) vs. Supply Voltage

Figure 11. Output Leak Current (DO) vs. Supply Voltage

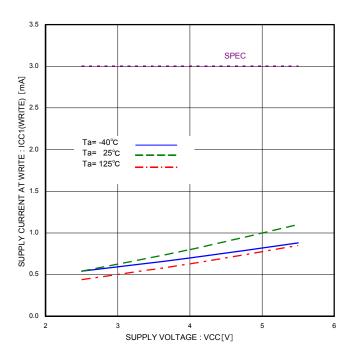


Figure 12. Supply Current at WRITE Operation vs. Supply Voltage (WRITE, fsk=2.0MHz)

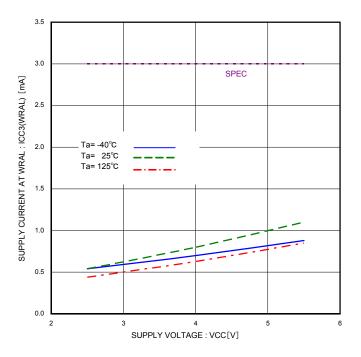


Figure 14. Supply Current at WRAL Operation vs. Supply Voltage (WRAL, f_{SK} =2.0MHz)

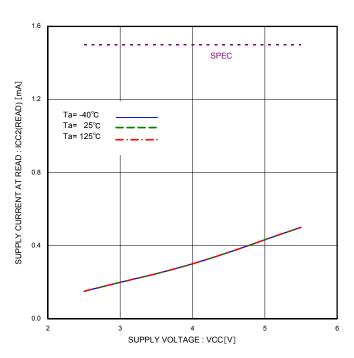


Figure 13. Supply Current at READ Operation vs. Supply Voltage (READ, fsk=2.0MHz)

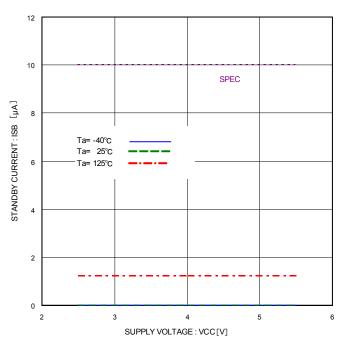


Figure 15. Standby Current vs. Supply Voltage

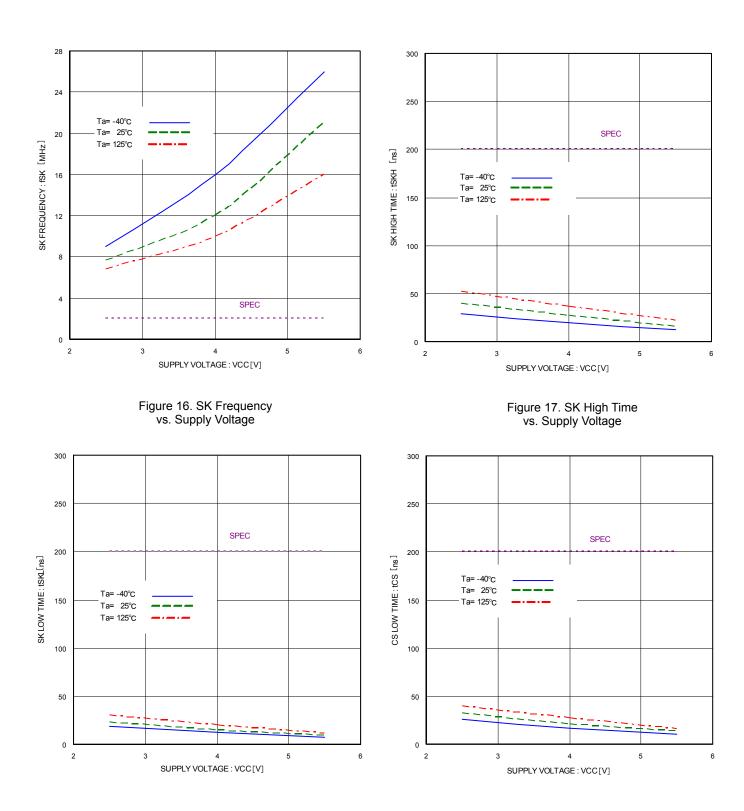
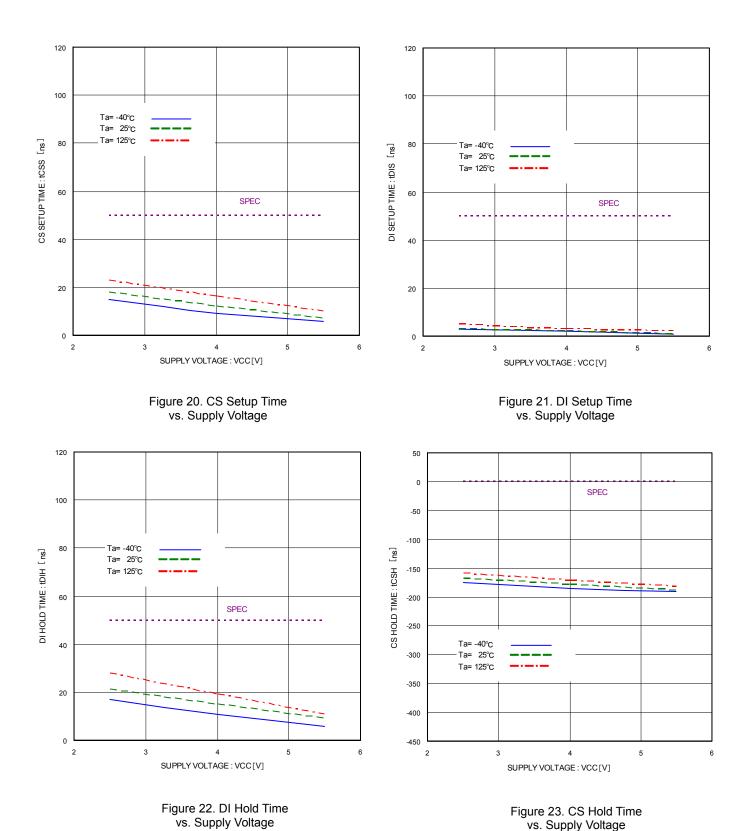
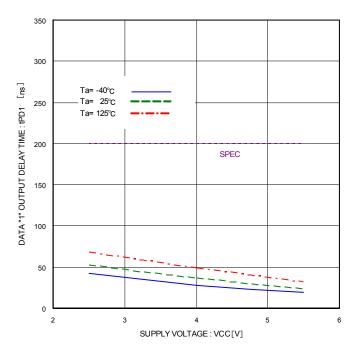


Figure 18. SK Low Time vs. Supply Voltage

Figure 19. CS Low Time vs. Supply Voltage





350

300

Ta= -40°C

Ta= 25°C

Ta= 125°C

Ta= 125°C

SPEC

SPEC

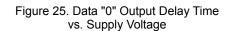
SPEC

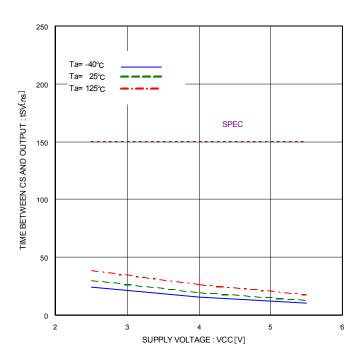
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Figure 24. Data "1" Output Delay Time vs. Supply Voltage





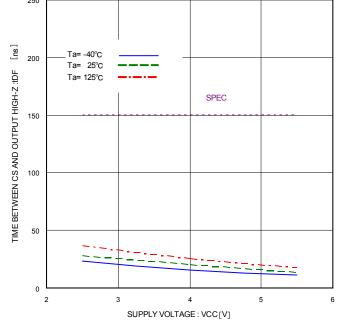


Figure 26. Time from CS Output establishment vs. Supply Voltage

Figure 27. Time from CS to High-Z vs. Supply Voltage

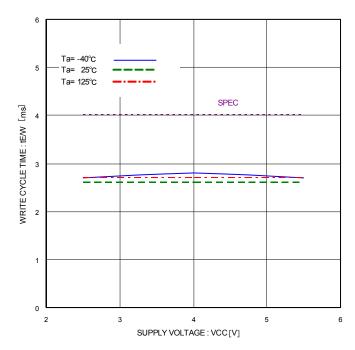


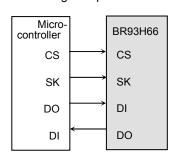
Figure 28. Write Cycle Time vs. Supply Voltage

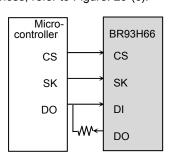
Description of Operation

Communications of the Microwire Bus are carried out by SK (serial clock), DI (serial data input),DO (serial data output) ,and CS (chip select) for device selection.

In connecting one EEPROM to a microcontroller, connect it as shown in Figure.29-(a) or Figure.29-(b). And, when using the input and output common I/O port of the microcontroller, connect DI and DO via a resistor as shown in Figure.29-(b) (Refer to pages 19/29), wherein connection by 3 lines is possible.

In case of using multiple EEPROM devices, refer to Figure. 29-(c).





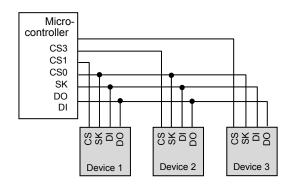


Figure 29-(a). Connection by 4 lines Figure 29-(b). Connection by 3 lines Figure 29-(c). Connection example of multiple devices

Figure 29. Connection Methods with Microcontroller

Communications of the Microwire Bus are started by the first "1" input after the rise of CS. This input is called the "Start Bit". After input of the start bit, the "Ope Code", Address, and Data are then inputted consecutively. Address and Data are all inputted with MSB first.

All "0" signal inputs after the rise of CS up to the start bit is ignored. Therefore, if there is a limitation in the bit width of PIC of the microcontroller, it is possible to input "0" before the start bit to control the bit width.

Command Mode

Command		Start bit	Ope code	Address BR93H66-2C	Data
Read (READ)	(1)	1	10	A7,A6,A5,A4,A3,A2,A1,A0	D15 to D0(READ DATA)
Write enable (WEN)		1	00	1 1 * * * * * *	-
Write (WRITE)	(2)	1	01	A7,A6,A5,A4,A3,A2,A1,A0	D15 to D0(WRITE DATA)
Write all (WRAL)	(2,3)	1	00	0 1 * * * * B0	D15 to D0(WRITE DATA)
Write disable (WDS)		1	00	00*****	-

Input the address and the data in MSB-first order.

Acceptance of all the commands of this IC starts at recognition of the start bit.

The "Start Bit" means the first "1" input after the rise of CS.

- (1) For READ, after setting the command, the data output of the selected address starts. Then, in a sequential order of addresses, the data of the next address will be outputted, and will continuously output data of succeeding addresses with the use of a continuous SK clock input. (Auto-Increment Function)
- (2) When the WRITE and the WRITE-All commands are executed, the previous data written in the selected memory cell are automatically deleted first, then the input data is written next.
- (3) For the WRITE-ALL command, data written in memory cell of the areas designated by B0 are automatically deleted, and input data is written in bulk.

Write All Area

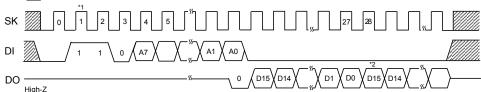
В0	Write Area
0	000h to 07Fh
1	080h to 0FFh

•The write all command is written in bulk in 2Kbit unit. The write area can be selected up to 1bit. Confirm on the left side the settings and write areas of B0.

As for *, input either V_{IH} or V_{IL}.

^{*}Start bit

Timing Chart



(1) Start bit

When data "1" is input for the first time after the rise of CS, this will be recognized as the start bit. And, even if multiple "0" are input after the rise of CS, the first "1" input will still be recognized as the start bit, and the following operation starts. This is common to all the commands that will be discussed hereafter.

(2) The succeeding address' data output (Auto-Increment Function)

Figure 30. Read Cycle

(1) When the READ command is recognized, the data (16bit) of the selected address is output to serial. And at that moment, "0" (dummy bit) is output first, in sync with address bit A0 and with the rise of SK. Afterwhich, the main data is output in sync with the rise of SK.

This IC has Address Auto Increment Function available only for READ command, wherein after executing READ command on the first selected address, the data of the next address is read. And this will continue in a sequential order of addresses with the use of a continuous SK clock input, and by keeping CS at "H" during auto-increment.

2. Write Cycle (WRITE)

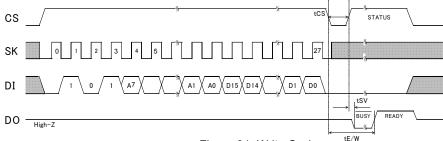


Figure 31. Write Cycle

(1) In this command, input 16-bit data (D15 to D0) are written to a designated address (A7 to A0). The actual write starts from the fall of CS, after D0 is sampled with SK clock (27th clock from the start bit input), to the rise of the 28th clock. When STATUS is not detected (CS="L" fixed), WRITE time is 4ms (Max.) in conformity with tE/W. And when STATUS is detected (CS="H"), all commands are not accepted for areas where "L" (BUSY) is output from D0. Therefore, do not input any command.

Write is not made or canceled if CS starts to fall after the rise of the 28th clock. Note) Take tSKH or more from the rise of the 27th clock to the fall of CS.

3. Write All Cycle (WRAL)

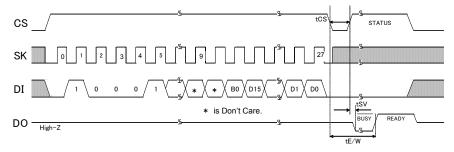


Figure 32. Write All Cycle

(1) In this command, input 16-bit data is written simultaneously to designated block for 128 words. Data is written in bulk at a write time of only 4ms (Max) in conformity with tew. When writing data to all addresses, designate each block by B0 and execute write. Write time is 4ms (Max).

The actual write starts from the fall of CS, after D0 is sampled with SK clock (27th clock from the start bit input), to the rise of the 28th clock. If CS was ended after the rise of the 28th clock, command is canceled, and write is not completed.

Note: Take tSKH or more from the rise of the 27th clock to the fall of CS.

4. Write Enable (WEN) / Disable (WDS) Cycle

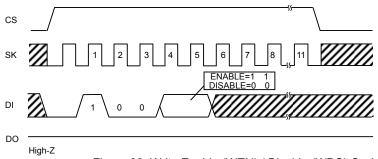


Figure 33. Write Enable (WEN) / Disable (WDS) Cycle

- (1) At power on, this IC is in Write Disable status by the internal RESET circuit. Before executing the WRITE command, it is necessary to execute the Write Enable command first. And, once this command is executed, writing is valid until the Write Disable command is executed or the power is turned off. However, the READ command is valid regardless of whether the Write Enable / Disable command is executed. Input to SK after 6 clocks of this command is available by either "H" or "L", but be sure to input it.
- (2) When the Write Enable command is executed after power on, Write Enable status gets in. When the Write Disable command is executed then, the IC gets in Write Disable status as same as at power on, and then the WRITE command is canceled thereafter in software manner. However, the READ command is still executable. In Write Enable status, even when the WRITE command is input by mistake, writing will still continue. To prevent such a mistake, it is recommended to execute the write disable command after the completion of each WRITE execution.

Application

1. Method to Cancel each Command

(1) READ

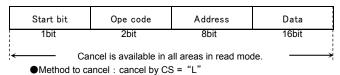
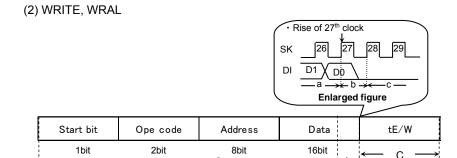


Figure 34. READ Cancel Available Timing



- a : From start bit to 27th clock rise Cancel by CS="L"
- b : 27th clock rise and after Cancellation is not available by any means. If Vcc is turned OFF in this area, designated address data is not guaranteed, therefore write once again.
- c : 28th clock rise and after
 Cancel by CS="L"
 However, when write is started in b area (CS is ended), cancellation is not available by any means.
 And when SK clock is input continuously, cancellation is not available.

Note 1) If Vcc is turned OFF in this area, designated address data is not guaranteed. Therefore, it is recommended to execute WRITE once again.

Note 2) If CS is started at the same timing as that of the SK rise, write execution/cancel becomes unstable. Therefore, it is recommended to set CS to "L" in SK="L" area. As for SK rise, recommended timing is of t_{CSS}/tC_{SH} or higher.

Figure 35. WRITE, WRAL Cancel Available Timing

I/O Equivalent Circuit (1) Output Circuit

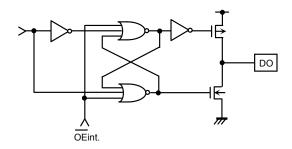


Figure 36. Output Circuit (DO)

(2) Input Circuit

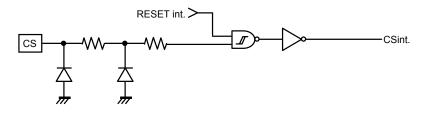


Figure 37. Input Circuit (CS)

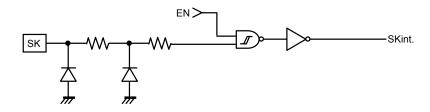


Figure 38. Input Circuit (SK)

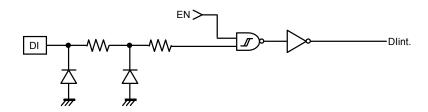


Figure 39. Input Circuit (DI)

3. I/O Peripheral Circuit

(1) Pull down CS

By making CS="L" at power ON/OFF, mistake in operation and mistake write are prevented.

(a) Pull down Resistance Rpd of CS pin

To prevent mistake in operation and mistake write at power ON/OFF, a CS pull down resistor is necessary. Select an appropriate resistance value from microcontroller's V_{OH}, I_{OH} and this IC's V_{IH} characteristics.

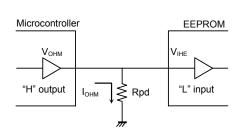


Figure 40. CS Pull down Resistance

$$R_{pd} \ge \frac{V_{OHM}}{I_{OHM}} \cdots \bigcirc$$

Example) When V_{CC} =5V, V_{IHE} =3.5V, V_{OHM} =4.0V, I_{OHM} =2mA, from the equation ①,

$$R_{pd} \ge \frac{4.0}{2 \times 10^{-3}}$$

$$R_{pd} \ge 2.0 [k\Omega]$$

With the value of Rpd satisfying the equation above, V_{OHM} becomes 4.0V or higher, and with V_{IHE} (=3.5V), equation ② is also satisfied.

V_{IHE} : EEPROM V_{IH} specifications
 V_{OHM} : Microcontroller V_{OH} specifications
 I_{OHM} : Microcontroller I_{OH} specifications

(2) DO is available for both pull up and pull down.

DO output is "High-Z" except during READY / BUSY output timing in WRITE command and, after data output at READ command. When malfunction occurs at "High-Z" input of the microcontroller port connected to DO, it is necessary to pull down and pull up DO. When there is no influence upon the microcontroller actions, DO may be left OPEN. If DO is OPEN during a transition of output from BUSY to READY status, and at an instance where CS="H", SK="H", DI="H", EEPROM recognizes this as a start bit, resets READY output, and sets DO="High-Z". Therefore, READY signal cannot be detected. To avoid such output, pull up DO pin for improvement.

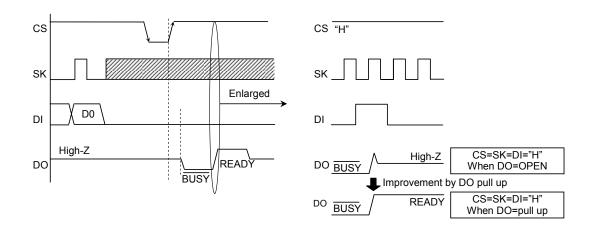


Figure 41. READY Output Timing at DO=OPEN

(a) Pull up Resistance Rpu and Pull down Resistance Rpd of DO pin

As for pull up and pull down resistance value, select an appropriate value to this resistance value from microcontroller V_{IH} , V_{IL} , and V_{OH} , I_{OH} , I_{OL} , I_{OL} characteristics of this IC.

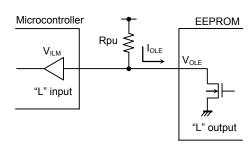


Figure 42. DO Pull up Resistance

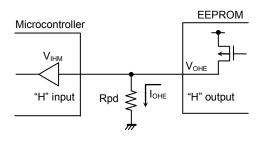


Figure 43. DO Pull down Resistance

$$Rpu \ge \frac{V_{cc} - V_{OLE}}{I_{OLE}} \qquad \cdots 3$$

$$V_{OLE} \le V_{ILM} \qquad \cdots 4$$

Example) When V_{CC} =5V, V_{OLE} =0.4V, I_{OLE} =2.1mA, V_{ILM} =0.8V, from the equation ③,

$$Rpu \ge \frac{5 - 0.4}{2.1 \times 10^{-3}}$$

$$Rpu \ge 2.2 [k\Omega]$$

With the value of Rpu to satisfy the above equation, V_{OLE} becomes 0.4V or below, and with V_{ILM} (=0.8V), the equation ④ is also satisfied.

Vole : EEPROM Vol specifications
 Iole : EEPROM Iol specifications
 VILM : Microcontroller VIL specifications

Example) When V_{CC} =5V, V_{OHE} =4.8V, I_{OHE} =0.1mA, V_{IHM} =3.5V from the equation (§)

$$Rpd \ge \frac{5 - 0.2}{0.1 \times 10^{-1}}$$

$$Rpd \ge 48 [k\Omega]$$

With the value of Rpd to satisfy the above equation, V_{OHE} becomes 4.8V or below, and with V_{IHM} (=3.5V), the equation 6 is also satisfied.

Vohe
 I EEPROM Voh specifications
 I EEPROM Ioh specifications
 VIHM
 Microcontroller VIH specifications

(b) READY / BUSY Status Display (DO terminal)

This display outputs the internal status signal. When CS is started after t_{CS} (Min.200ns) from CS fall after write command input, "H" or "L" output.

 R/\overline{B} display="L" (\overline{BUSY}) = write under execution

(DO status) After the timer circuit in the IC works and creates the period of t_{EW}, this time circuit completes automatically. And write to the memory cell is made in the period of t_{EW}, and during this period, other command is not accepted.

 R/\overline{B} display = "H" (READY) = command wait status

Even after t_{E/W} (Max.4ms) from write of the memory cell, the following command is accepted.

Therefore, CS="H" in the period of t_{E/W}, and when input is in SK, DI, malfunction may occur, Therefore, set DI="L" in the area CS="H". (Especially, in the case of shared input port, attention is required.)

*Do not input any command while status signal is output. Command input in BUSY area is canceled, but command input in READY area is accepted. Therefore, status READY output is canceled, and malfunction and mistake write may be made.

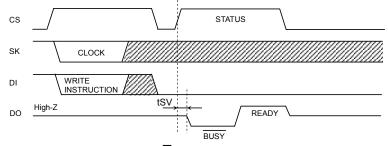


Figure 44. R/B Status Output Timing Chart

4. When to directly connect DI and DO

This IC has independent input terminal DI and output terminal DO, wherein signals are handled separately on timing chart. But,, by inserting a resistance R between these DI and DO terminals, it is possible to carry out control by only 1 control line.

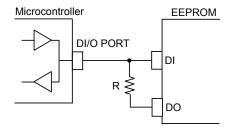


Figure 45. DI, DO Control Line Common Connection

- OData collision of microcontroller DI/O output and DO output and feedback of DO output to DI input. Drive from the microcontroller DI/O output to DI input on I/O timing, and signal output from DO output occur at the same time in the following points.
- (1) 1 clock cycle to take in A0 address data at read command Dummy bit "0" is output to DO terminal.
 - →When address data A0 = "1" input, through current route occurs.

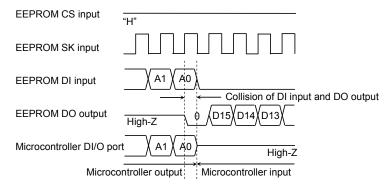


Figure 46. Collision timing at read data output at DI, DO direct connection

(2) Timing of CS = "H" after write command. DO terminal in READY / BUSY function output.

When the next start bit input is recognized, "HIGH-Z" gets in.

→Especially, at command input after write, when CS input is started with microcontroller DI/O output "L",

READY output "H" is output from DO terminal, and through current route occurs.

Feedback input at timing of these 4-1) and 4-2) does not cause disorder in basic operations, if resistance R is inserted.

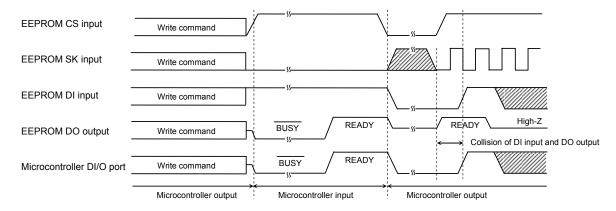


Figure 47. Collision timing at DI, DO direct connection

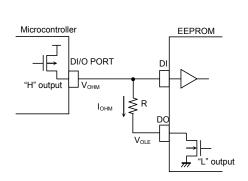
(a) Selection of Resistance Value R

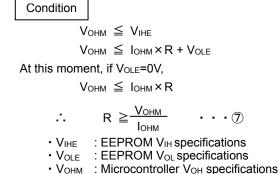
The resistance R becomes through current limit resistance at data collision. When through current flows, noises of power source line and instantaneous stop of power source may occur. When allowable through current is defined as I, the following relation should be satisfied. Determine allowable current amount in consideration of impedance and so forth of power source line in set. And insert resistance R, and set the value R to satisfy EEPROM input level V_{IH}/V_{IL} , even under influence of voltage decline owing to leak current and so forth. Insertion of R will not cause any influence upon basic operations.

(3) Address data A0 = "1" input, dummy bit "0" output timing

(When microcontroller DI/O output is "H", EEPROM DO outputs "L", and "H" is input to DI)

- · Make the through current to EEPROM 10mA or below.
- See to it that the input level V_{IH} of EEPROM should satisfy the following.





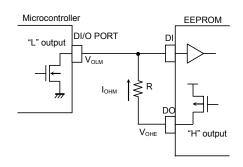
: Microcontroller I_{OH} specifications

Figure 48. Circuit at DI, DO direct connection (Microcontroller DI/O "H" output, EEPROM "L" output)

(4) DO status READY output timing

(When the microcontroller DI/O is "L", EEPROM DO outputs "H", and "L" is input to DI)

Set the EEPROM input level V_{IL} so as to satisfy the following.



$$\begin{array}{ccc} V_{OLM} \; \geqq \; V_{ILE} \\ V_{OLM} \; \geqq \; V_{OHE} - I_{OLM} \times R \\ \\ \text{As this moment, if } V_{OHE} = V_{cc}, \\ V_{OLM} \; \geqq \; V_{cc} - I_{OLM} \times R \end{array}$$

$$\therefore \qquad R \ge \frac{V_{cc} - V_{OLM}}{I_{OLM}} \qquad \cdots \quad \underline{\$}$$

V_{ILE} : EEPROM V_{IL} specifications
 V_{OHE} : EEPROM V_{OH} specifications
 V_{OLM} : Microcontroller V_{OL} specifications
 I_{OLM} : Microcontroller I_{OL} specifications

Example) When V_{CC}=5V, V_{OHM}=5V, I_{OHM}=0.4mA, V_{OLM}=0.4V, I_{OLM}=2.1mA,

From the equation 7,

$$R \ge \frac{V_{OHM}}{I_{OHM}}$$

$$R \ge \frac{5}{0.4 \times 10^{-3}}$$

$$\therefore \qquad R \, \geqq \, 12.5 \, [k \, \Omega] \qquad \cdot \cdot \cdot \cdot \, \textcircled{9}$$

From the equation (8),

Condition

$$R \ge \frac{1}{10 \text{LM}}$$

$$R \ge \frac{5 - 0.4}{2.1 \times 10^{-3}}$$

$$R \ge 2.2 [k\Omega] \cdots \mathbb{D}$$

Therefore, from the equations (9) and (10),

$$\therefore$$
 R \geq 12.5 [k Ω]

Figure 49. Circuit at DI, DO direct connection (Microcontroller DI/O "L" output, EEPROM "H" output)

5. Power-Up/Down Conditions

· At power ON/OFF, set CS "L".

When CS is "H", this IC gets in input accept status (active). At power ON, set CS "L" to prevent malfunction from noise. (When CS is in "L" status, all inputs are canceled.) At power decline low power status may prevail. Therefore, at power OFF, set CS "L" to prevent malfunction from noise.

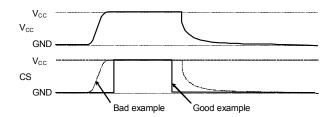


Figure 50. Timing at Power ON/OFF

(Bad example) CS pin is pulled up to Vcc.

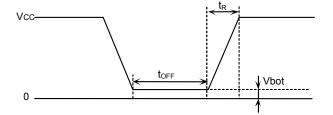
In this case, CS becomes "H" (active status), EEPROM may malfunction or have write error due to noises. This is true even when CS input is High-Z.

(Good example) It is "L" at power ON/OFF. Set 10ms or higher to recharge at power OFF. When power is turned on without observing this condition, IC internal circuit may not be reset.

(1) POR Circuit

This IC has a POR (Power On Reset) circuit as a mistake write countermeasure. After POR action, it gets in write disable status. The POR circuit is valid only when power is ON, and does not work when power is OFF. However, if CS is "H" at power ON/OFF, it may become write enable status owing to noises and the likes. For secure actions, observe the following conditions.

- 1. Set CS="L"
- 2. Turn on power so as to satisfy the recommended conditions of tR, toff, Vbot for POR circuit action.



Recommended conditions of tR, tOFF, Vbot

t _R	t _{OFF}	Vbot
10ms or below	10ms or higher	0.3V or below
100ms or below	10ms or higher	0.2V or below

Figure 51. Rise Waveform Diagram

(2) L_{VCC} Circuit

L_{VCC} (V_{CC}-Lockout) circuit prevents data rewrite action at low power, and prevents wrong write. At L_{VCC} voltage (Typ=1.9V) or below, it prevents data rewrite.

6. Noise Countermeasures

(1) V_{CC} noise (bypass capacitor)

When noise or surge gets in the power source line, malfunction may occur. Therefore, in removing these, it is recommended to attach a bypass capacitor (0.1 μ F) between IC V_{CC} and GND as close to IC as possible. It is also recommended to attach a bypass capacitor between board V_{CC} and GND.

(2) SK noise

When the rise time (t_R) of SK is long, and a certain degree or more of noise exists, malfunction may occur owing to clock bit displacement.

To avoid this, a Schmitt trigger circuit is built in SK input. The hysteresis width of this circuit is set about 0.2V. If noise exists at SK input, set the noise amplitude 0.2Vp-p or below. And it is recommended to set the rise time (t_R) of SK to 100ns or below. In the case when the rise time is 100ns or higher, take sufficient noise countermeasures. Make the clock rise, fall time as small as possible.

Operational Notes

1. Described numeric values and data are design representative values, and the values are not guaranteed.

2. Application Circuit

Although we can recommend the application circuits contained herein with a relatively high degree of confidence, we ask that you verify all characteristics and specifications of the circuit as well as its performance under actual conditions. Please note that we cannot be held responsible for problems that may arise due to patent infringements or noncompliance with any and all applicable laws and regulations.

3. Absolute Maximum Ratings

Operating the IC over the absolute maximum ratings may damage the IC. The damage can either be a short circuit between pins or an open circuit between pins. Therefore, it is important to consider circuit protection measures, such as adding a fuse, in case the IC is operated over the absolute maximum ratings.

4. Ground Voltage

The voltage of the ground pin must be the lowest voltage of all pins of the IC at all operating conditions. Ensure that no pins are at a voltage below the ground pin at any time, even during transient condition.

5. Thermal Consideration

Use a thermal design that allows for a sufficient margin by taking into account the permissible power dissipation (Pd) in actual operating conditions. Consider Pc that does not exceed Pd in actual operating conditions (Pc≥Pd).

Package Power dissipation : Pd (W)= $(T_{imax}-T_a)/\theta$ ja

Power Dissipation : $Pc(W)=(V_{CC}-V_0)\times lo+V_{cc}\times lb$

T_{jmax}: Maximum junction temperature=150°C, Ta: Peripheral temperature[°C],

 θ ja : Thermal resistance of package-ambience[°C/W], Pd : Package Power dissipation [W], Pc : Power dissipation [W], Vcc : Input Voltage, Vo : Output Voltage, Io : Load, Ib : Bias Current

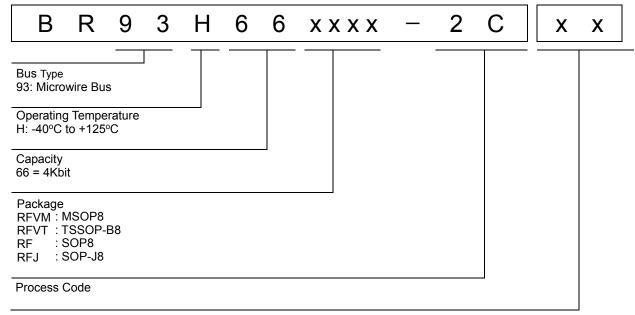
6. Short between pins and mounting errors

Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.

7. Operation under strong electromagnetic field

Operating the IC in the presence of a strong electromagnetic field may cause the IC to malfunction.

Part Numbering



Package Specifications

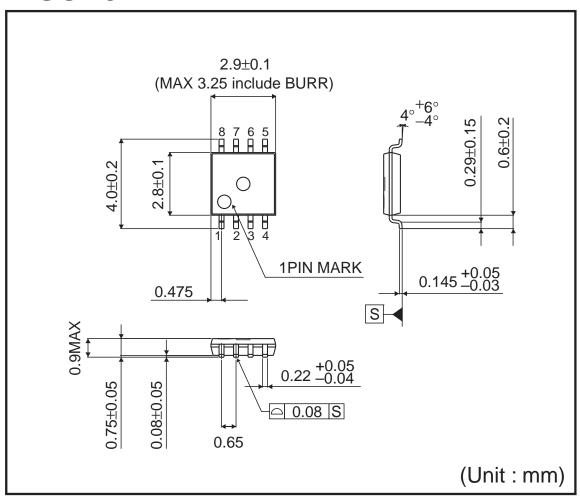
TR : reel shape emboss taping (MSOP8) E2 : reel shape emboss taping (TSSOP-B8, SOP8, SOP-J8)

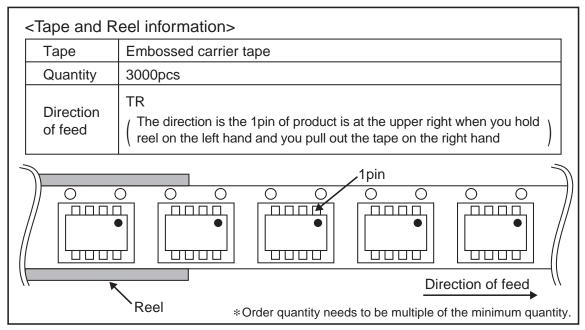
Lineup

чр						
Consoity	Pac	Package Orderable Port Num				
Capacity	Acity Type Quantity Orderab MSOP8 Reel of 3000 BR93H6 K SOP8 BR93H	Orderable Part Number				
	MSOP8	Dool of 2000	BR93H66RFVM-2CTR			
412	TSSOP-B8	Reel of 3000	BR93H66RFVT-2CE2			
4K	SOP8	Dool of 2500	BR93H66RF-2CE2			
	SOP-J8	Reel of 2500	BR93H66RFJ-2CE2			

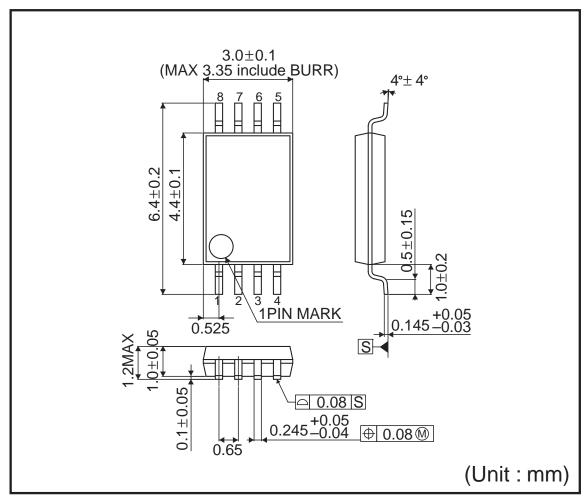
Physical Dimentions, Tape and Reel Infomation

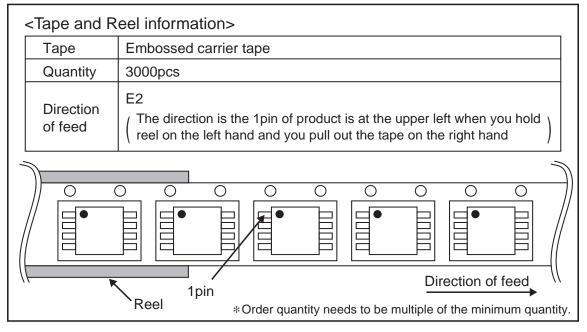
MSOP8



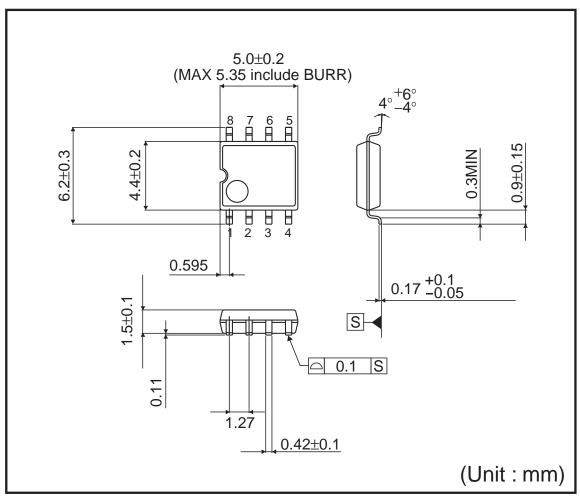


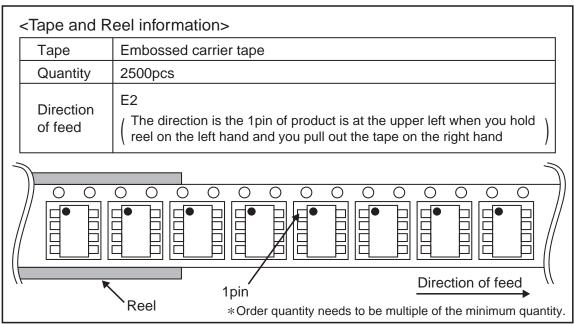
TSSOP-B8



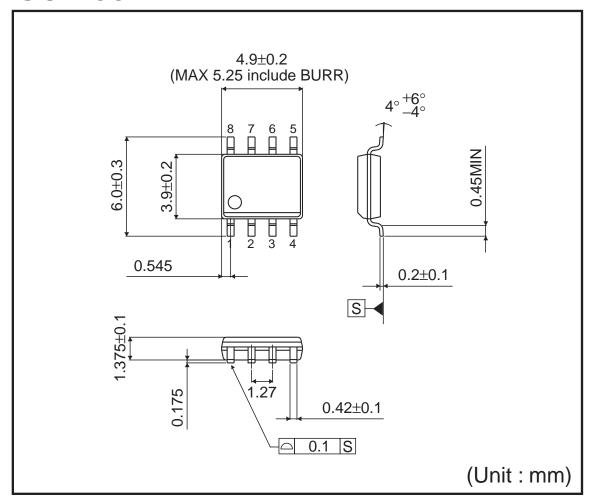


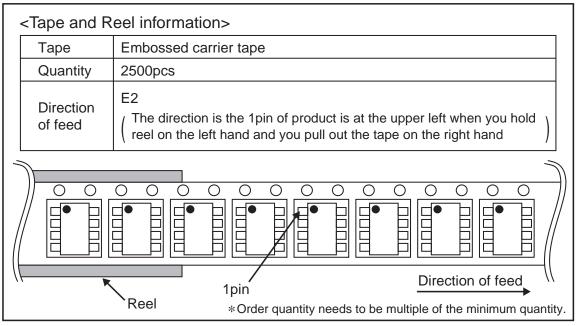
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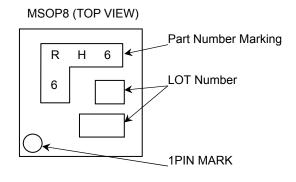


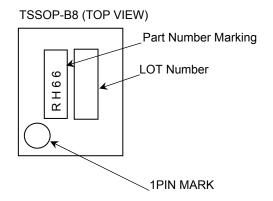
SOP-J8

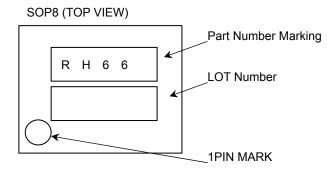


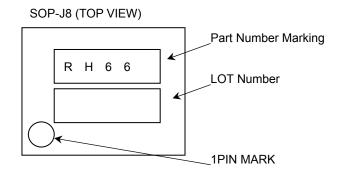


Marking Diagrams









Capacity	Product Name Marking	Package Type
		MSOP8
412	RH66	TSSOP-B8
4K		SOP8
		SOP-J8

Revision History

Date	Revision	Changes		
31.Aug.2012	001	New Release		
19.Dec.2012	002	All page P2	Document converted to new format. Data Retention was changed.	
01.Dec.2015	Dec.2015 003		Data Retention and Write Cycles were modified. Graph of Figure 4. was modified. Reference Page Number was modified. Bit B2 and B1 were removed. Comments in WRAL were modified and added. Figure 31. and Figure 32. were modified. Text Bugs were modified in Figure 42.and Figure 44	

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- 1			=	
	JAPAN	USA	EU	CHINA
	CLASSⅢ	CLASSIII	CLASS II b	CLASSIII
	CLASSIV	CLASSIII	CLASSⅢ	

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 - [h] Use of the Products in places subject to dew condensation
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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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